

## SBRD5150 SCHOTTKY RECTIFIER

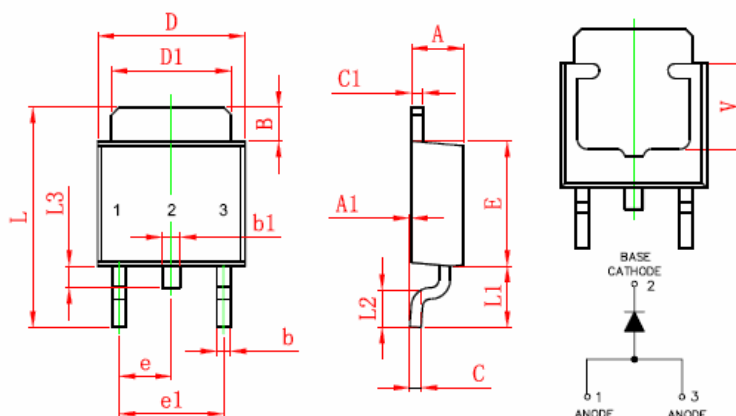
### Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Features:

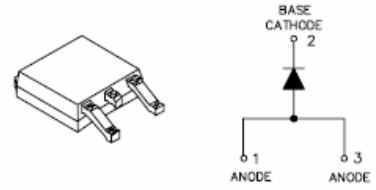
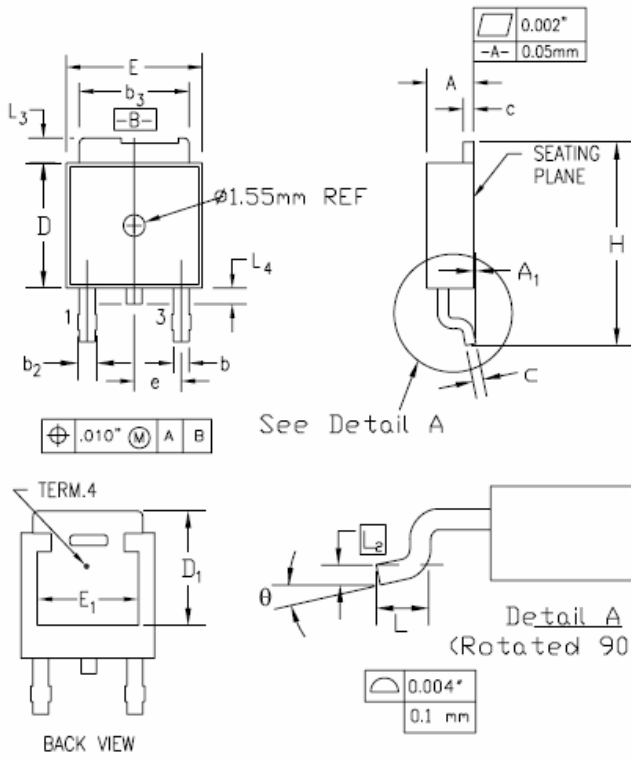
- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Dimensions: In Inches / mm:



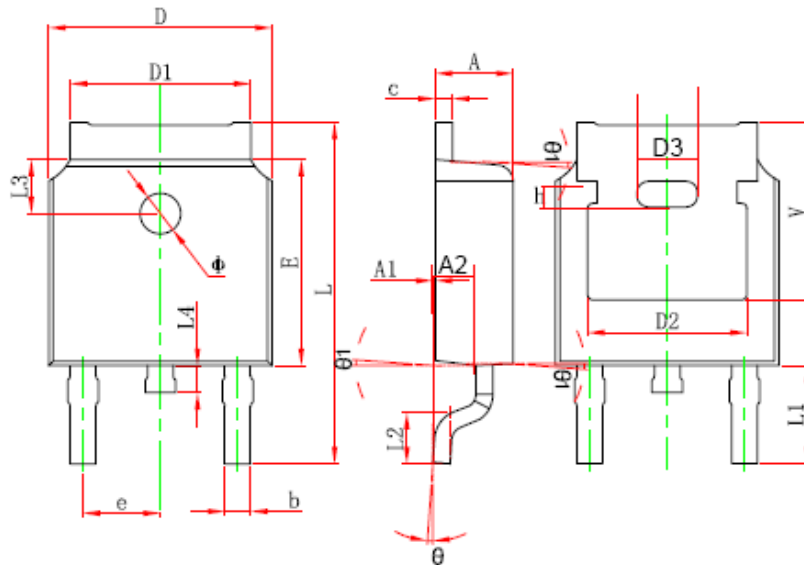
Symbol	Dimensions in Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
B	1.350	1.650	0.053	0.065
b	0.500	0.700	0.020	0.028
b1	0.700	0.900	0.028	0.035
c	0.430	0.580	0.017	0.023
c1	0.430	0.580	0.017	0.023
D	6.350	6.650	0.250	0.262
D1	5.200	5.400	0.205	0.213
E	5.400	5.700	0.213	0.224
e	2.300 TYP.		0.091 TYP.	
e1	4.500	4.700	0.177	0.185
L	9.500	9.900	0.374	0.390
L1	2.550	2.900	0.100	0.114
L2	1.400	1.780	0.055	0.070
L3	0.600	0.900	0.024	0.035
V	3.800 REF.		0.150 REF.	

### OPTION 1

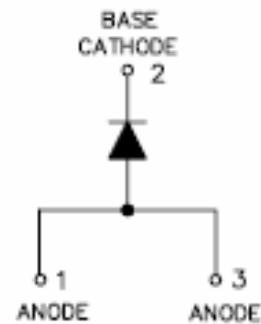


SYMBOL	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.19	2.38
A <sub>1</sub>	—	0.005	—	0.13
b	0.025	0.035	0.64	0.89
b <sub>2</sub>	0.033	0.045	0.84	1.14
b <sub>3</sub>	0.205	0.215	5.21	5.46
c	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
D <sub>1</sub>	0.205	—	5.21	—
E	0.250	0.265	6.35	6.73
E <sub>1</sub>	0.190	—	4.83	—
e	0.090	BSC	2.29	BSC
H	0.380	0.410	9.65	10.41
L	0.055	0.070	1.40	1.78
L <sub>2</sub>	0.020	BSC	0.51	BSC
L <sub>3</sub>	0.035	0.050	0.89	1.27
L <sub>4</sub>	0.025	0.040	0.64	1.01
$\theta$	0°	8°	0°	8°

**OPTION 2(MX)**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
A2	0.910	1.110	0.036	0.044
V	5.350 REF.		0.211 REF.	
D3	1.778 REF.		0.070 REF.	
h	0.762 REF.		0.030 REF.	
θ1	7°		7°	



**OPTION 3(CJ)**

**DPAK**

**Marking Diagram:**



Where XXXXX is YYWWL

SBR = Device Type  
D = Package type  
5 = Forward Current (5A)  
150 = Reverse Voltage (150V)  
SSG = SSG  
YY = Year  
WW = Week  
L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
SBRD5150	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	150	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @ $T_C=105^\circ\text{C}$ , rectangular wave form	5	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	$I_{FSM}$	8.3 ms, half Sine pulse	60	A

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V <sub>F1</sub>	@ 3A, Pulse, T <sub>J</sub> = 25 °C @ 5A, Pulse, T <sub>J</sub> = 25 °C	0.90 1.00	V
	V <sub>F2</sub>	@ 3A, Pulse, T <sub>J</sub> = 125 °C @ 5A, Pulse, T <sub>J</sub> = 125 °C	0.75 0.85	V
Max. Reverse Current at DC Condition	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	5.0	mA
Max. Junction Capacitance	C <sub>T</sub>	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	100	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

\* Pulse Width < 300μs, Duty Cycle <2%

**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T <sub>J</sub>	-	-55 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	6	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

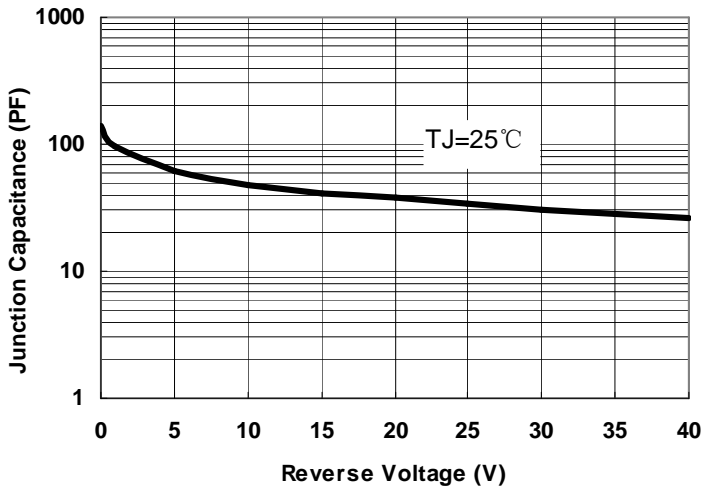


Fig.1-Typical Junction Capacitance

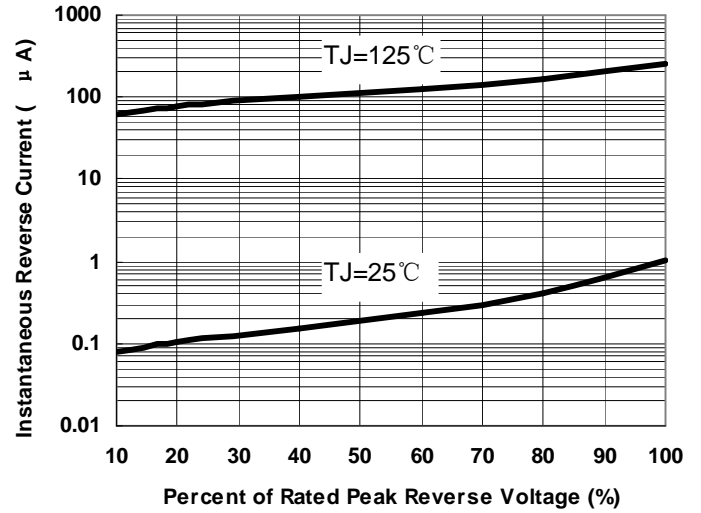


Fig.2-Typical Reverse Characteristics

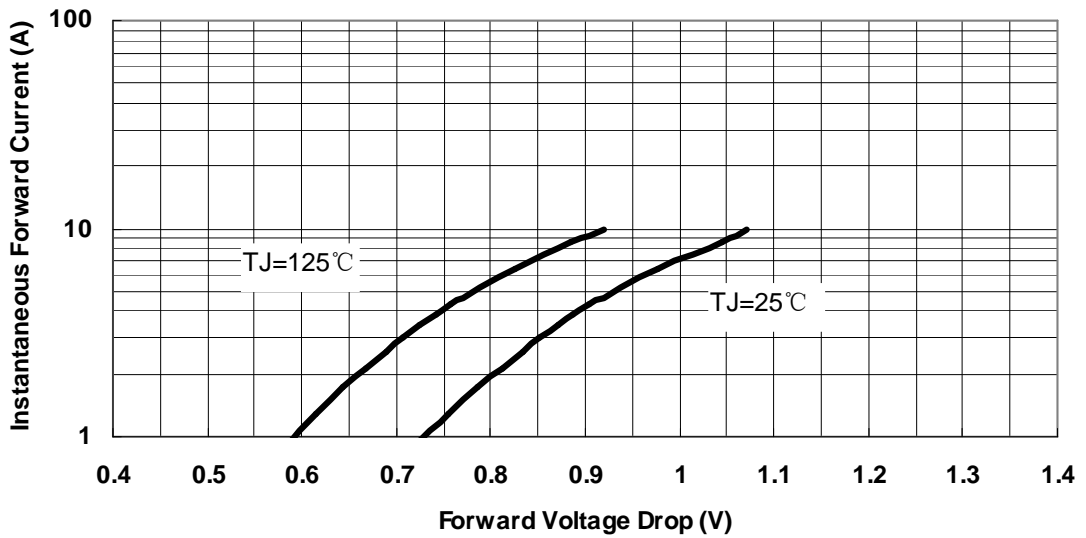


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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